This question paper contains 2 printed pages]

NY-314-2023

FACULTY OF SCIENCE

M.Sc. (Second Semester) EXAMINATION

NOVEMBER/DECEMBER, 2023

(New/CBCS Pattern)

PHYSICS

Paper-PHY-204

(Condensed Matter Physics)

(Wednesday, 13-12-2023) Time: 10.00 a.m. to 1.00 p.m.					
\overline{Time}	2—3 <i>H</i>	ours	AR ART	Maximum Ma	arks—75
1.		in Bragg's law of X en two crystalline	- (a)	d obtain an expression for	spacing 15
	(a)	Explain types of	surface defects.	Ay, Ob. 84	8
9	(b)	Explain reciproca	al lattice of FCC i	s BCC.	7
2.		in in detail the Blo I to find the band		s implementation in Kroni id.	ig-Penny 15
A.D.	(a)	Explain Agument of the solid.	ed plane wave mo	del to calculate the band s	structure 7
	(b)	Explain electron	motion in one-din	nensional crystal lattice.	8
3.	Explain in detail the Hall effect to determine the carrier concentration and mobility in a semiconductor.				
			Or		
	(a)		rmi level in n-type and conduction ba	e and p-type semiconduct and.	or shifts 8
	(b) S	Define Ferroelect	ricity in detail.		7
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4.	Explain the formation of M-H curve in ferromagnetic materials.
	Or Constant in detail the Leader posteration denth
	(a) Explain in detail the London penetration depth. 7
	(b) Explain the Curie Weiss law for susceptibility. 8
5.	Write short notes on any three of the following:
	(i) Cooper pair
	(ii) The cellular method
	(iii) The dipolar dispersion in solids
	(iv) Diamond structure.
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